RENESAS BCR12CS-12LB

Triac

Medium Power Use

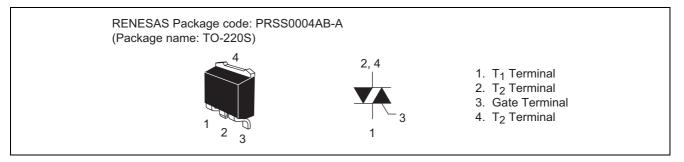
(The product guaranteed maximum junction temperature of 150°C)

REJ03G0470-0300 Rev.3.00 Nov 30, 2007

Features

- I_{T (RMS)} : 12 A
- V_{DRM} : 600 V
- I_{FGTI} , I_{RGTI} , $I_{RGT III}$: 30 mA (20 mA)^{Note6}

Outline



Non-Insulated Type

Planar Passivation Type

Applications

Contactless AC switch, light dimmer, electronic flasher unit, control of household equipment such as TV sets, stereo systems, refrigerator, washing machine, infrared kotatsu, carpet, electric fan, solenoid driver, small motor control, solid state relay, copying machine, electric tool, electric heater control, and other general purpose control applications

Warning

- 1. Refer to the recommended circuit values around the triac before using.
- 2. Be sure to exchange the specification before using. Otherwise, general triacs with the maximum junction temperature of 125°C will be supplied.

Maximum Ratings

| Parameter | Symbol | Voltage class | Unit | |
|--|------------------|---------------|------|--|
| | - | 12 | | |
| Repetitive peak off-state voltage ^{Note1} | V _{DRM} | 600 | V | |
| Non-repetitive peak off-state voltage ^{Note1} | V _{DSM} | 720 | V | |

BCR12CS-12LB (The product guaranteed maximum junction temperature of 150°C)

| Parameter | Symbol | Ratings | Unit | Conditions |
|--------------------------------|----------------------|--------------|------------------|--|
| RMS on-state current | I _{T (RMS)} | 12 | A | Commercial frequency, sine full wave 360° conduction, Tc = $123^{\circ}C^{Note3}$ |
| Surge on-state current | I _{TSM} | 120 | A | 60Hz sinewave 1 full cycle, peak value, non-repetitive |
| l ² t for fusing | l ² t | 60 | A ² s | Value corresponding to 1 cycle of half wave 60Hz, surge on-state current |
| Peak gate power dissipation | P _{GM} | 5 | W | |
| Average gate power dissipation | P _{G (AV)} | 0.5 | W | |
| Peak gate voltage | V _{GM} | 10 | V | |
| Peak gate current | I _{GM} | 2 | Α | |
| Junction temperature | Tj | - 40 to +150 | °C | |
| Storage temperature | Tstg | - 40 to +150 | °C | |
| Mass | — | 1.2 | g | Typical value |

Notes: 1. Gate open.

Electrical Characteristics

| Parameter | | Symbol | Min. | Тур. | Max. | Unit | Test conditions |
|---|-----|-----------------------|---------|------|---------------------|------|--|
| Repetitive peak off-state current | | I _{DRM} | — | _ | 2.0 | mA | Tj = 150°C, V _{DRM} applied |
| On-state voltage | | V _{TM} | — | _ | 1.6 | V | $Tc = 25^{\circ}C$, $I_{TM} = 20$ A, Instantaneous measurement |
| Gate trigger voltage ^{Note2} | Ι | V_{FGTI} | — | _ | 1.5 | V | $Tj = 25^{\circ}C, V_D = 6 V, R_L = 6 \Omega,$ |
| | II | V _{RGTI} | — | _ | 1.5 | V | $R_{G} = 330 \Omega$ |
| | III | V _{RGTIII} | — | _ | 1.5 | V | |
| Gate trigger current ^{Note2} | Ι | I _{FGTI} | _ | | 30 ^{Note6} | mA | $Tj = 25^{\circ}C, V_D = 6 V, R_L = 6 \Omega,$ |
| | II | I _{RGTI} | — | _ | 30 ^{Note6} | mA | $R_G = 330 \Omega$ |
| | III | I _{RGTIII} | — | _ | 30 ^{Note6} | mA | |
| Gate non-trigger voltage | | V_{GD} | 0.2/0.1 | _ | _ | V | $Tj = 125^{\circ}C/150^{\circ}C, V_{D} = 1/2 V_{DRM}$ |
| Thermal resistance | | R _{th (j-c)} | — | _ | 1.8 | °C/W | Junction to case ^{Note3 Note4} |
| Critical-rate of rise of off-state commutating voltage ^{Note5} | | (dv/dt)c | 10/1 | _ | — | V/µs | Tj = 125°C/150°C |

Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

3. Case temperature is measured on the T_2 tab.

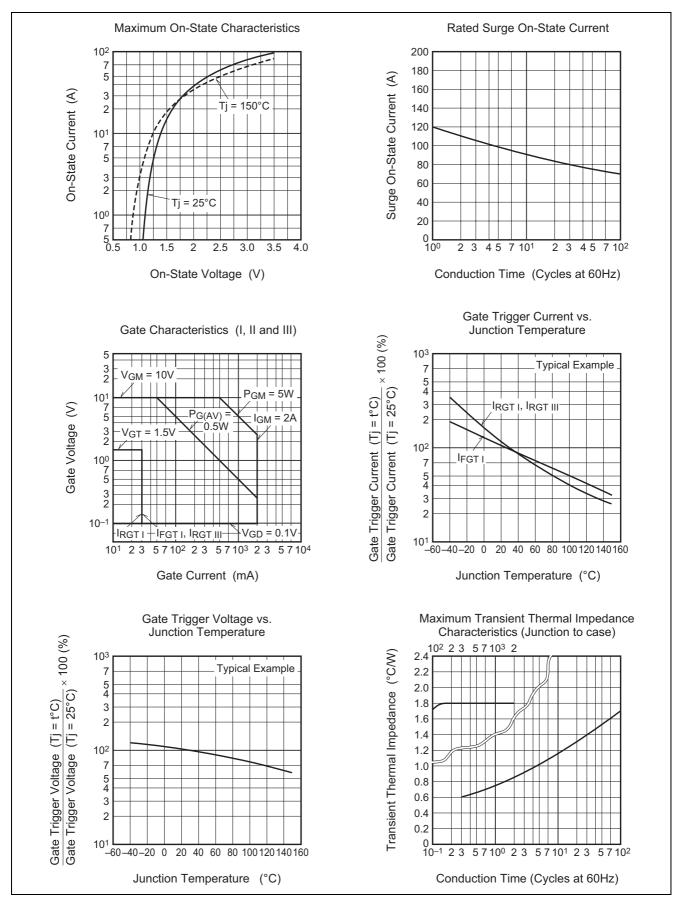
4. The contact thermal resistance $R_{th\,(c\text{-}f)}$ in case of greasing is 1.0°C/W.

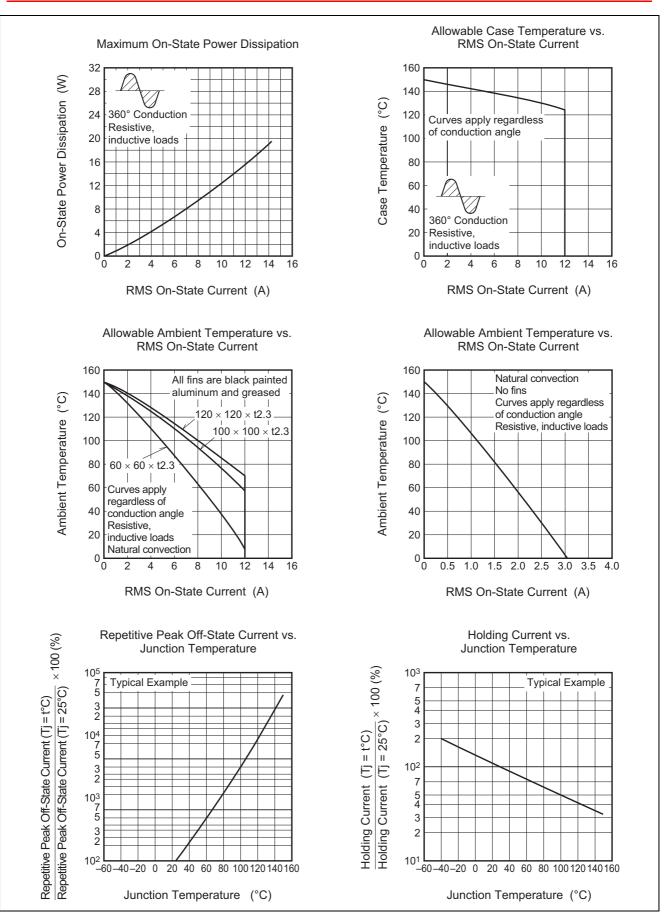
5. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

6. High sensitivity (I_{GT} ≤ 20 mA) is also available. (I_{GT} item: 1)

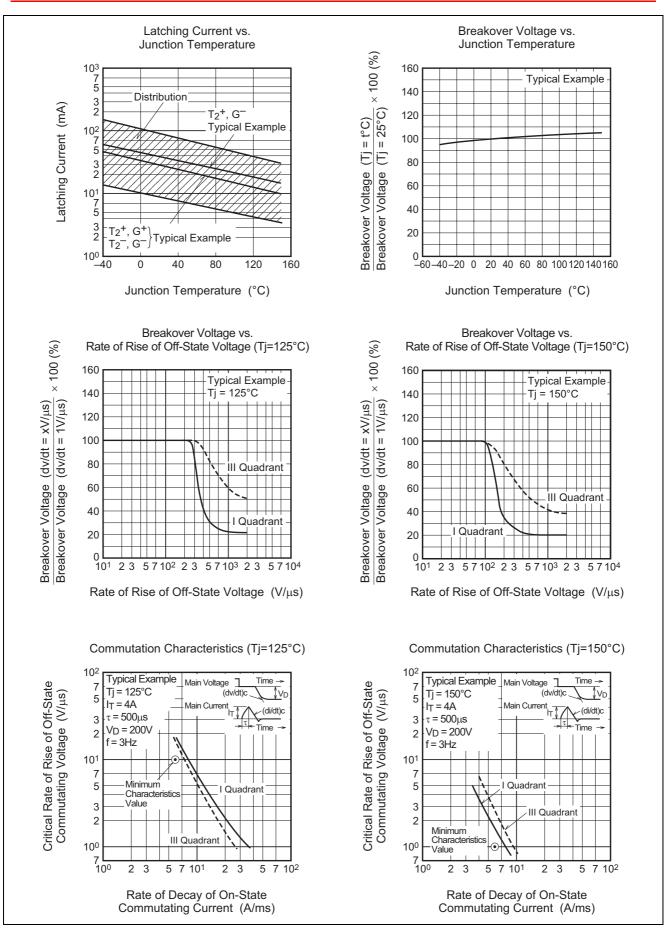
| Test conditions | Commutating voltage and current waveforms (inductive load) |
|---|--|
| 1. Junction temperature Tj = 125°C/150°C | Supply Voltage → Time |
| 2. Rate of decay of on-state commutating current (di/dt)c = - 6.0 A/ms | Main Current → Time |
| 3. Peak off-state voltage $V_D = 400 \text{ V}$ | Main Voltage → Time (dv/df)c V _D |

Performance Curves

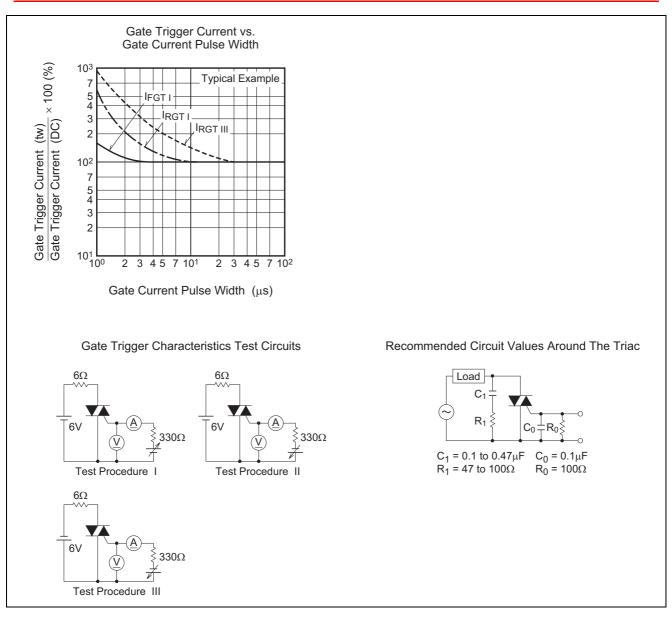




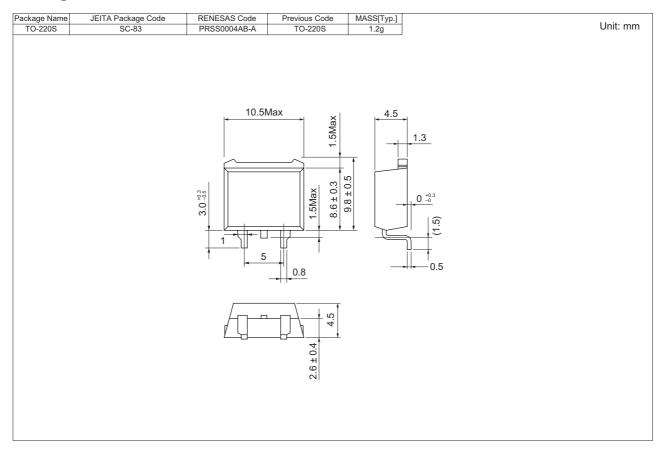
BCR12CS-12LB (The product guaranteed maximum junction temperature of 150°C)



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Package Dimensions



Order Code

| Lead form | Standard packing | Quantity | Standard order code | Standard order code example |
|----------------------|----------------------------|----------|--------------------------------------|--------------------------------|
| Surface-mounted type | Taping | 1000 | Type name – T +Direction (1 or 2) +1 | BCR12CS-12LB-T11 |
| Surface-mounted type | Plastic Magazine (Tube) | 50 | Type name | BCR12CS-12LB |

Note : Please confirm the specification about the shipping in detail.

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